## Integrated Relay, Inductive Load Driver

This device is used to switch inductive loads such as relays, solenoids incandescent lamps, and small DC motors without the need of a free-wheeling diode. The device integrates all necessary items such as the MOSFET switch, ESD protection, and Zener clamps. It accepts logic level inputs thus allowing it to be driven by a large variety of devices including logic gates, inverters, and microcontrollers.

## Features

- Provides a Robust Driver Interface Between D.C. Relay Coil and Sensitive Logic Circuits
- Optimized to Switch Relays of 12 V Rail
- Capable of Driving Relay Coils Rated up to 6.0 W at 12 V
- Internal Zener Eliminates the Need of Free-Wheeling Diode
- Internal Zener Clamp Routes Induced Current to Ground for Quieter Systems Operation
- Low V $\mathrm{DS}(\mathrm{ON})$ Reduces System Current Drain
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are $\mathrm{Pb}-$ Free Devices


## Typical Applications

- Telecom: Line Cards, Modems, Answering Machines, FAX
- Computers and Office: Photocopiers, Printers, Desktop Computers
- Consumer: TVs and VCRs, Stereo Receivers, CD Players, Cassette Recorders
- Industrial: Small Appliances, Security Systems, Automated Test Equipment, Garage Door Openers


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MARKING DIAGRAMS


JW5 = Specific Device Code
M = Date Code

- = Pb-Free Package
(Note: Microdot may be in either location)


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M = Date Code

- $\quad=$ Pb-Free Package
(Note: Microdot may be in either location)


## ORDERING INFORMATION

| Device | Package | Shipping ${ }^{\dagger}$ |
| :--- | :---: | :---: |
| NUD3112LT1G | SOT-23 <br> $($ Pb-Free) |  <br> Reel |
| SZNUD3112LT1G | SOT-23 <br> (Pb-Free) |  <br> Reel |
| NUD3112DMT1G | SC-74 <br> (Pb-Free) |  <br> Reel |
| SZNUD3112DMT1G | SC-74 <br> (Pb-Free) |  <br> Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

INTERNAL CIRCUIT DIAGRAMS



MAXIMUM RATINGS $\left(T_{J}=25^{\circ} \mathrm{C}\right.$ unless otherwise specified)

| Symbol | Rating |  | Value | Unit |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {DSS }}$ | Drain to Source Voltage - Continuous |  | 14 | $\mathrm{V}_{\mathrm{dc}}$ |
| $V_{G S}$ | Gate to Source Voltage - Continuous |  | 6 | $\mathrm{V}_{\mathrm{dc}}$ |
| ID | Drain Current - Continuous |  | 500 | mA |
| $\mathrm{E}_{\mathrm{z}}$ | Single Pulse Drain-to-Source Avalanche Energy ( $\mathrm{T}_{\text {Jinitial }}=25^{\circ} \mathrm{C}$ ) |  | 50 | mJ |
| $\mathrm{T}_{J}$ | Junction Temperature |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{A}}$ | Operating Ambient Temperature |  | -40 to 85 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ | Storage Temperature Range |  | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{P}_{\mathrm{D}}$ | Total Power Dissipation (Note 1) Derating Above $25^{\circ} \mathrm{C}$ | SOT-23 | $\begin{gathered} 225 \\ 1.8 \end{gathered}$ | $\begin{gathered} \mathrm{mW} \\ \mathrm{~mW} /{ }^{\circ} \mathrm{C} \end{gathered}$ |
| $\mathrm{P}_{\mathrm{D}}$ | Total Power Dissipation (Note 1) Derating Above $25^{\circ} \mathrm{C}$ | SC-74 | $\begin{gathered} \hline 380 \\ 3.0 \end{gathered}$ | $\begin{gathered} \mathrm{mW} \\ \mathrm{~mW} /{ }^{\circ} \mathrm{C} \end{gathered}$ |
| $\mathrm{R}_{\theta \mathrm{JA}}$ | Thermal Resistance Junction-to-Ambient (Note 1) | $\begin{array}{r} \hline \text { SOT-23 } \\ \text { SC-74 } \end{array}$ | $\begin{aligned} & 556 \\ & 329 \end{aligned}$ | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| ESD | Human Body Model (HBM) According to EIA/JESD22/A114 |  | 2000 | V |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Mounted onto minimum pad board.

TYPICAL ELECTRICAL CHARACTERISTICS ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| Symbol | Characteristic | Min | Typ | Max | Unit |
| :--- | :--- | :--- | :--- | :--- | :--- |

OFF CHARACTERISTICS

| $\mathrm{V}_{\text {BRDSS }}$ | Drain to Source Sustaining Voltage (Internally Clamped) $(\mathrm{l} D=10 \mathrm{~mA})$ | 14 | 16 | 17 | V |
| :---: | :---: | :---: | :---: | :---: | :---: |
| BVGSo | $\mathrm{I}_{\mathrm{g}}=1.0 \mathrm{~mA}$ | - | - | 8 | V |
| IDSs | Drain to Source Leakage Current $\begin{aligned} & \left(\mathrm{V}_{\mathrm{DS}}=12 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right) \\ & \left(\mathrm{V}_{\mathrm{DS}}=12 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=85^{\circ} \mathrm{C}\right. \end{aligned}$ | - | - | $\begin{aligned} & 20 \\ & 40 \end{aligned}$ | $\mu \mathrm{A}$ |
| IGSs | Gate Body Leakage Current $\begin{aligned} & \left(\mathrm{V}_{\mathrm{GS}}=3.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0 \mathrm{~V}\right) \\ & \left(\mathrm{V}_{\mathrm{GS}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0 \mathrm{~V}\right) \end{aligned}$ | - | - | $\begin{aligned} & 35 \\ & 65 \end{aligned}$ | $\mu \mathrm{A}$ |

ON CHARACTERISTICS

| $\mathrm{V}_{\mathrm{GS}}(\mathrm{th})$ | Gate Threshold Voltage $\begin{aligned} & \left(V_{G S}=V_{D S}, I_{D}=1.0 \mathrm{~mA}\right) \\ & \left(V_{G S}=V_{D S}, I_{D}=1.0 \mathrm{~mA}, \mathrm{~T}_{A}=85^{\circ} \mathrm{C}\right) \end{aligned}$ | $\begin{aligned} & 0.8 \\ & 0.8 \end{aligned}$ | 1.2 | $\begin{aligned} & 1.4 \\ & 1.4 \end{aligned}$ | V |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{R}_{\mathrm{DS} \text { (on) }}$ | Drain to Source On-Resistance $\begin{aligned} & \left(l_{\mathrm{D}}=250 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=3.0 \mathrm{~V}\right) \\ & \left(\mathrm{I}_{\mathrm{D}}=500 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=3.0 \mathrm{~V}\right) \\ & \left(\mathrm{I}_{\mathrm{D}}=500 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=5.0 \mathrm{~V}\right) \\ & \left(\mathrm{I}_{\mathrm{D}}=500 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=3.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=85^{\circ} \mathrm{C}\right) \\ & \left(\mathrm{I}_{\mathrm{D}}=500 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=5.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=85^{\circ} \mathrm{C}\right) \end{aligned}$ |  | - | $\begin{aligned} & 1.2 \\ & 1.3 \\ & 0.9 \\ & 1.3 \\ & 0.9 \end{aligned}$ | $\Omega$ |
| $\mathrm{I}_{\text {DS(on) }}$ | Output Continuous Current $\begin{aligned} & \left(\mathrm{V}_{\mathrm{DS}}=0.25 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=3.0 \mathrm{~V}\right) \\ & \left(\mathrm{V}_{\mathrm{DS}}=0.25 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=3.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=85^{\circ} \mathrm{C}\right) \end{aligned}$ | $\begin{aligned} & 300 \\ & 200 \end{aligned}$ | 400 | - | mA |
| grs | Forward Transconductance <br> ( $\mathrm{V}_{\text {OUT }}=12.0 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=0.25 \mathrm{~A}$ ) | 350 | 490 | - | mmhos |

TYPICAL ELECTRICAL CHARACTERISTICS ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| Symbol | Characteristic | Min | Typ | Max | Unit |
| :--- | :--- | :--- | :--- | :--- | :--- |

DYNAMIC CHARACTERISTICS

| $\mathrm{C}_{\text {iss }}$ | Input Capacitance <br> $\left(\mathrm{V}_{\mathrm{DS}}=12 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{f}=10 \mathrm{kHz}\right)$ | - | 23 | - | pF |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{C}_{\mathrm{oss}}$ | Output Capacitance <br> $\left(\mathrm{V}_{\mathrm{DS}}=12 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{f}=10 \mathrm{kHz}\right)$ | - | 30 | - | pF |
| $\mathrm{C}_{\mathrm{rss}}$ | Transfer Capacitance <br> $\left(\mathrm{V}_{\mathrm{DS}}=12.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{f}=10 \mathrm{kHz}\right)$ | - | 7 | - | pF |

SWITCHING CHARACTERISTICS

| Symbol | Characteristic | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{\text {PHL }}$ tpLH | Propagation Delay Times: <br> High to Low Propagation Delay; Figure $1\left(\mathrm{~V}_{\mathrm{DS}}=12 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=5.0 \mathrm{~V}\right)$ <br> Low to High Propagation Delay; Figure $1\left(\mathrm{~V}_{\mathrm{DS}}=12 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=5.0 \mathrm{~V}\right)$ | - | $\begin{aligned} & 21 \\ & 91 \end{aligned}$ | - | nS |
| $\begin{aligned} & \mathrm{t}_{\mathrm{f}} \\ & \mathrm{t}_{\mathrm{r}} \end{aligned}$ | Transition Times: <br> Fall Time; Figure $1\left(\mathrm{~V}_{\mathrm{DS}}=12 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=5.0 \mathrm{~V}\right)$ <br> Rise Time; Figure $1\left(\mathrm{~V}_{\mathrm{DS}}=12 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=5.0 \mathrm{~V}\right)$ | - | $\begin{aligned} & 36 \\ & 61 \end{aligned}$ | - | nS |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.


Figure 1. Switching Waveforms

## NUD3112

TYPICAL PERFORMANCE CURVES $\left(\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}\right.$ unless otherwise specified)


Figure 2. Output Characteristics


Figure 4. On-Resistance Variation vs. Temperature


Figure 6. Zener Voltage vs. Temperature


Figure 3. Transfer Function


Figure 5. $\mathrm{R}_{\mathrm{DS}(\mathrm{ON})}$ Variation vs. Gate-to-Source Voltage


Figure 7. Zener Clamp Voltage vs. Zener Current

## NUD3112

TYPICAL PERFORMANCE CURVES $\left(\mathrm{T}_{J}=25^{\circ} \mathrm{C}\right.$ unless otherwise specified)


Figure 8. On-Resistance vs. Drain Current and Temperature


Figure 9. Gate Leakage vs. Temperature


Figure 10. Typical Application Circuit


SOT-23 (TO-236)
CASE 318-08
ISSUE AS
DATE 30 JAN 2018

## SCALE 4:1



NOTES:
IMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994
. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

|  | MILLIMETERS |  |  | INCHES |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 0.89 | 1.00 | 1.11 | 0.035 | 0.039 | 0.044 |
| A1 | 0.01 | 0.06 | 0.10 | 0.000 | 0.002 | 0.004 |
| b | 0.37 | 0.44 | 0.50 | 0.015 | 0.017 | 0.020 |
| $\mathbf{c}$ | 0.08 | 0.14 | 0.20 | 0.003 | 0.006 | 0.008 |
| D | 2.80 | 2.90 | 3.04 | 0.110 | 0.114 | 0.120 |
| E | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| e | 1.78 | 1.90 | 2.04 | 0.070 | 0.075 | 0.080 |
| L | 0.30 | 0.43 | 0.55 | 0.012 | 0.017 | 0.022 |
| L1 | 0.35 | 0.54 | 0.69 | 0.014 | 0.021 | 0.027 |
| $\mathbf{H E}_{\mathbf{E}}$ | 2.10 | 2.40 | 2.64 | 0.083 | 0.094 | 0.104 |
| T | $0^{\circ}$ | --- | $10^{\circ}$ | $0^{\circ}$ | --- | $10^{\circ}$ |

GENERIC
MARKING DIAGRAM*

RECOMMENDED SOLDERING FOOTPRINT


DIMENSIONS: MILLIMETERS


XXX = Specific Device Code
M = Date Code

- = Pb-Free Package
*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " $\quad$ ", may or may not be present.


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SC-74
CASE 318F
ISSUE P
SCALE 2:1


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